

View Online at <https://aerobasegroup.com/nsn/5961-00-240-6483>

Inclosure Material:

Metal

Overall Length:

0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

-50.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor and -0.7 peak-point voltage all transistor and -4.0 peak-point voltage all transistor

Power Rating Per Characteristic:

300.0 milliwatts total device dissipation all transistor

Maximum Operating Temperature Per Measurement Point:

55.0 degrees celsius ambient air

Special Features:

Matched to within 5.5 millivolts over a temperature range of -30c to +55c.

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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